

Fuji Discrete Package IGBT

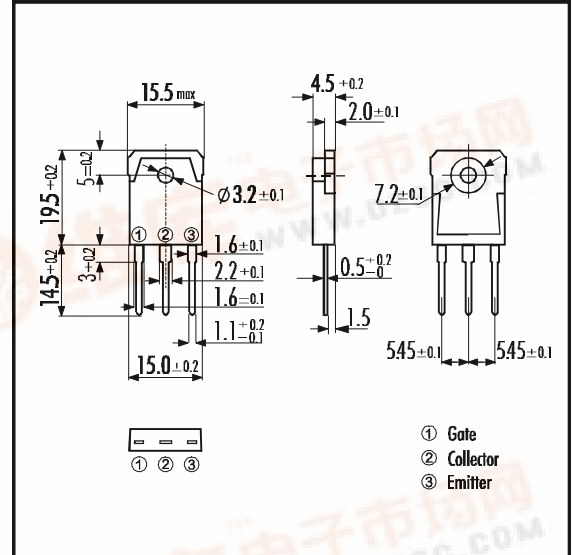
Outline Drawing

Features

- Square RBSOA
- Low Saturation Voltage
- Less Total Power Dissipation
- Minimized Internal Stray Inductance

Applications

- High Power Switching
- A.C. Motor Controls
- D.C. Motor Controls
- Uninterruptible Power Supply

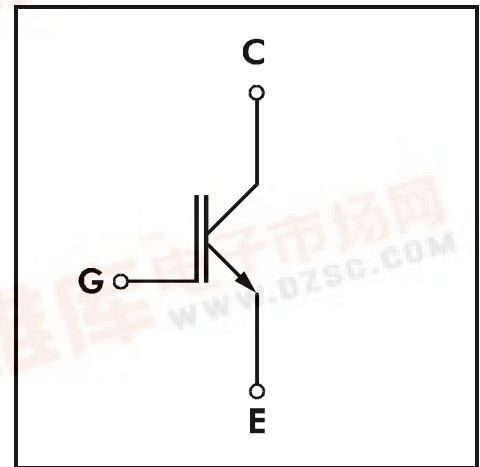


Maximum Ratings and Characteristics

Equivalent Circuit

Absolute Maximum Ratings (T_c=25°C)

Items	Symbols	Ratings	Units
Collector-Emitter Voltage	V _{CEs}	1200	V
Gate -Emitter Voltage	V _{GES}	± 20	V
Collector Current	DC T _c = 25°C	I _{C 25}	16
	DC T _c =100°C	I _{C 100}	10
	1ms T _c = 25°C	I _{C PULSE}	48
IGBT Max. Power Dissipation	P _C	135	W
Operating Temperature	T _j	+150	°C
Storage Temperature	T _{stg}	-40 ~ +150	°C
Mounting Screw Torque		50	Nm



Electrical Characteristics (at T_j=25°C)

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units	
Zero Gate Voltage Collector Current	I _{CES}	V _{GE} =0V V _{CE} =1200V			1.0	mA	
Gate-Emitter Leakage Current	I _{GES}	V _{CE} =0V V _{GE} =± 20V			20	μA	
Gate-Emitter Threshold Voltage	V _{GE(th)}	V _{GE} =20V I _C =10mA	5.5		8.5	V	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} =15V I _C =10A			3.5	V	
Input capacitance	C _{ies}	V _{GE} =0V		1200		pF	
Output capacitance	C _{oes}	V _{CE} =10V		250			
Reverse Transfer capacitance	C _{res}	f=1MHz		80			
Switching Time	Turn-on Time	t _{ON}	V _{CC} =600V			1.2	μs
		t _r	I _C =10A			0.6	
	Turn-off Time	t _{OFF}	V _{GE} =±15V			1.5	
		t _f	R _G =160Ω			0.5	
	Turn-on Time	Turn-on Time	t _{ON}	V _{CC} =600V		0.16	μs
			t _r	I _C =10A		0.11	
Turn-off Time		t _{OFF}	V _{GE} =+15V		0.30		
		t _f	R _G =16Ω		0.5		

Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	R _{th(j-c)}				0.92	°C/W



